

Abstract

Characterization of thin porous copper layers designed for two-phase heat dissipation was conducted through measuring resistance of the dry samples as a proxy for thermal conductivity and by measuring heat dissipation via boiling with pressurized water as the working fluid. Phase separation membranes were liquid/vapor applied control to distribution. Challenges associate with making these measurements on thin porous films were explored.

Motivation

Microelectronic components are becoming smaller and more powerful, while at the same time consumer devices are increasing the number and power of these components. Dissipating heat is thus becoming a limiting factor for future developments of these devises. Dr. Goodson's lab is exploring both the transport of heat through the components of microelectronics and innovative methods of cooling these components.

SEM of Porous Copper Layer



Bright rings encircle pores left by the polystyrene template. Black holes in the pores are openings for the movement of fluid.



CENTER FOR POWER OPTIMIZATION OF ELECTRO-THERMAL SYSTEMS

The NanoHeat group in Dr. Goodson's shown excellent heat labs has dissipation via boiling in thin, porous copper layers. The inverse opal layers are created using a template of packed polystyrene microspheres on a silicon substrate. Copper is electroplated around this template, which is then dissolved in an organic solvent, THF, leaving the porous copper layer. Open channels in the layer, caused by sintering the polystyrene spheres of the template, allow water to travel through the layer. Vaporization of the liquid near the surface of the layer results in highly effective heat transfer away from the porous layer and heat source.



Thermal conductivity is an important characteristic of porous media for convective heat transfer, but is difficult to measure in thin layers. I, therefore, electrical resistivity the explored of use measurements as a proxy for thermal conductivity.

Because of the small size and irregular perimeter of the copper layers it was hoped that van der Pauw resistance measurements would be convenient.

Measurements by this method were tested in several configurations and with probes of various metals at different gauges. Unfortunately, the method proved inconsistent with the highly conductive copper.

Properties of Thin Porous Copper Layers for Dissipating Thermal Energy from Microelectronics

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Introduction

Pressurized Water Assembly Diagram



Water, constant under pressure, enters the system to be vaporized in the heated porous copper.

Results

Our experiment indicates that the pressure of water can be used to change the operating temperature at the porous copper Further work will continue to bridge. correlate the pressure and temperature dependence and to use new dielectric liquids to widen the range of temperatures.

Resistance Measurements of Thin Porous Copper Films

Testing of Laser Cut Porous Copper Bridge



An acrylic template guides resistance leads to reproducible placement on the sample

Characterization of Thin Porous Copper Layers Designed for Two-Phase Heat Dissipation

Separation of Liquid and Vapor



Liquid water is unable to pass through the PTFE layer, but water vapor created by boiling does pass through, carrying heat away from the system.

Testing of the Porous Copper Bridge



When the system is operating, the resistance is measured as With current is increased. data from a reference resistor, the temperature at the bridge can be calculated.

Conclusions

The micrometer thick porous copper layer My work in the lab has helped me is a promising, developing technology appreciate the challenges of cuttingedge engineering like this work, the being characterized in Dr. Goodson's lab. Its small size makes it not only suitable thoughtfulness and persistence of the for at-site cooling purposes of powerful multidisciplinary researchers, the electronic components, but also makes it explorations in nature of new engineering, and shown me a glimpse challenging to characterize. of the future of microelectronics.

Laser cutting a serpentine through the samples path provided more reproducible resistance measurements 4-point collinear using a measurement.

Resistance compared was with bulk copper in foil form. The porous copper provides resistances $\sim 3.5x$ that of the foil, and shows an acceptable measurement error of $\sim 10\%$.

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Outreach.

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Data & Analysis

Temperature Differences

in Two-Phase Heat **Dissipation Experiment at Different Pressures** * 2psi * 4psi 12psi 14psi /**/_ ₽[°] 100

Temperature ^oC

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